Diode Semiconductor Device - Page 1 of 1



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Inclos	ure Material:
Ceram	ic and metal
Overa	II Length:
0.820	nches
Overa	II Diameter:
0.294	nches
Mount	ing Method:
Termir	al
Featu	es Provided:
Herme	tically sealed case
Semic	onductor Material:
Silicon	
Power	Rating Per Characteristic:
1.0 wa	tts power output and 250.0 milliwatts small-signal output power, common-base minor
Maxim	um Operating Tempurature Per Measurement Point:
150.0	degrees celsius ambient air
Specia	al Features:
Band of	-x; test freq 9375mhz; freq range 4000 to 10000hz
Precio	us Material:
Gold o	r silver
Termi	nal Type And Quantity:
1 bear	n lead and 1 ferrule
Specif	ication Data:
80131	release6701 professional/industrial association specification
Shelf	_ife:
N/a	
Unit O	f Measure:
Demili	tarization:
Yes - o	lemil/mli
Fiig:	
A110a	0